

MSKSEMI

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

Product data sheet



SMC

FEATURES

- * Ideal for surface mount applications
- * Easy pick and place
- * Built-in strain relief
- * Fast switching speed

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Metallurgically bonded construction
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.21 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| P/N(MARK) | US3A | US3B | US3D | US3E | US3G | US3J | US3K | US3M | UNITS |
|---|------------|------|------|------|------|------|------|------|-------|
| Maximum Recurrent Peak Reverse Voltage | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | 35 | 70 | 140 | 210 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Rectified Current at Ta=55°C | 3.0 | | | | | | | | A |
| Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method) | 100 | | | | | | | | A |
| Maximum Instantaneous Forward Voltage at 3.0A | 1.0 | | 1.3 | | 1.85 | | | | V |
| Maximum DC Reverse Current Ta=25°C | 10 | | | | | | | | μA |
| at Rated DC Blocking Voltage Ta=100°C | 200 | | | | | | | | μA |
| Maximum Reverse Recovery Time (Note 1) | 50 | | | | 75 | | | | nS |
| Typical Junction Capacitance (Note 2) | 75 | | | | | | | | pF |
| Operating and Storage Temperature Range T _J , T _{STG} | -65 — +150 | | | | | | | | °C |

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (US3A THRU US3M)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

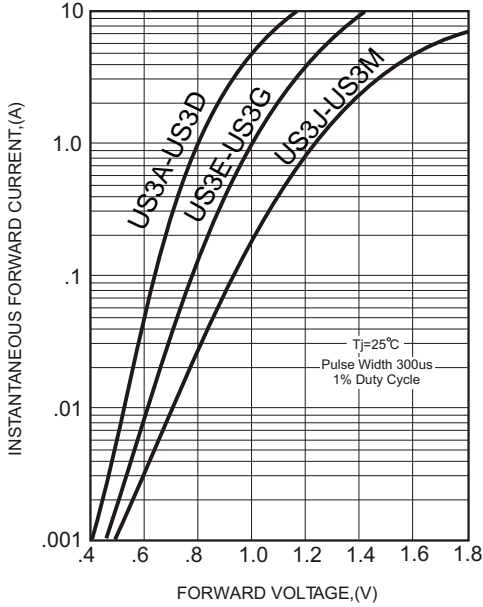


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

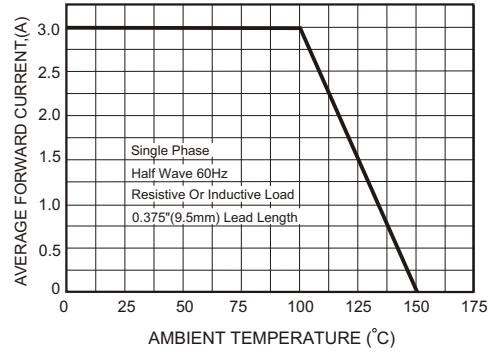


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

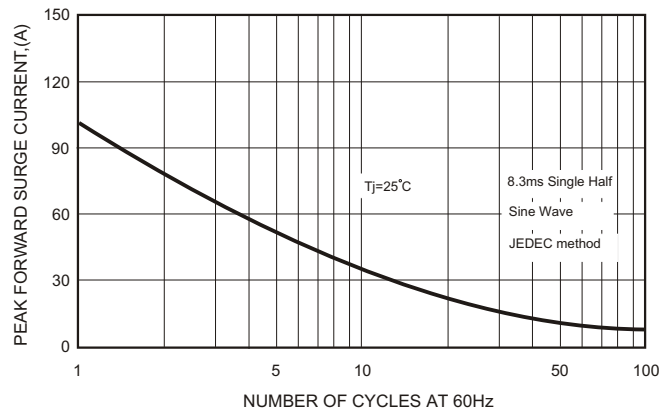
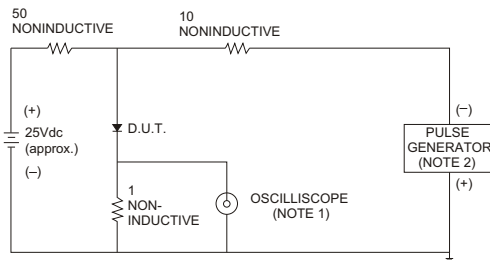


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

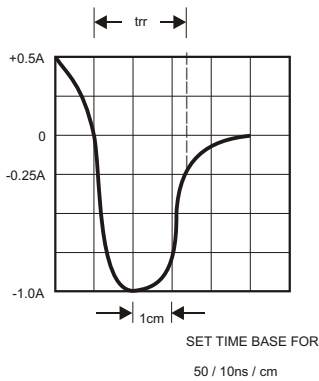
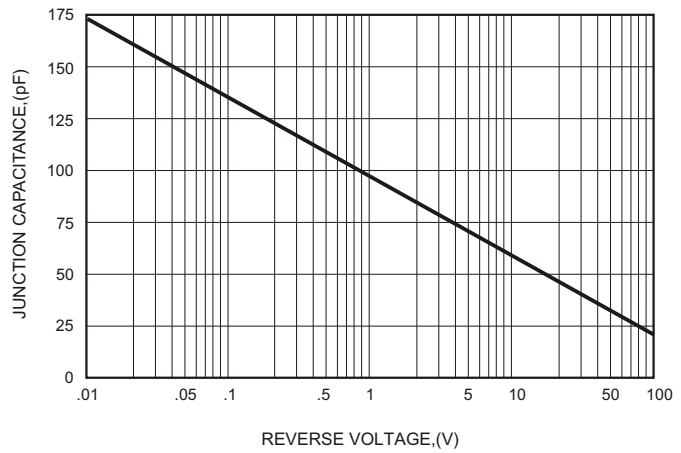
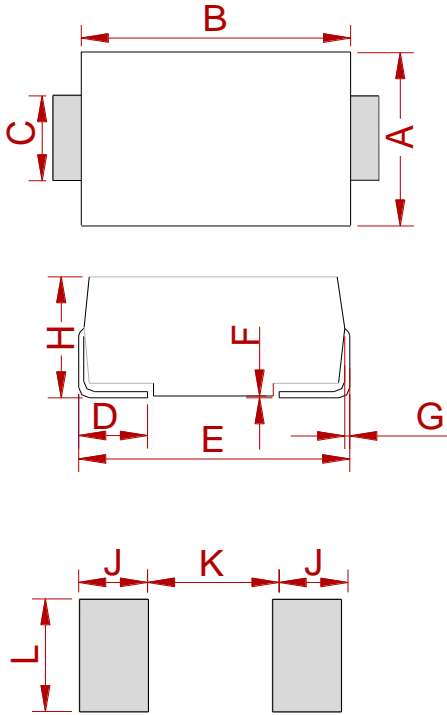


FIG.5-TYPICAL JUNCTION CAPACITANCE



PACKAGE MECHANICAL DATA



SMC

| Ref. | Dimensions | | | |
|------|-------------|-------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 5.75 | 6.25 | 0.226 | 0.246 |
| B | 6.90 | 7.40 | 0.272 | 0.291 |
| C | 2.75 | 3.25 | 0.108 | 0.128 |
| D | 0.95 | 1.52 | 0.037 | 0.060 |
| E | 7.70 | 8.20 | 0.303 | 0.323 |
| F | 0.051 | 0.203 | 0.002 | 0.008 |
| G | 0.15 | 0.31 | 0.006 | 0.012 |
| H | 2.15 | 2.62 | 0.085 | 0.103 |
| J | 2.40 | | 0.094 | |
| K | | 4.20 | | 0.165 |
| L | 3.30 | | 0.130 | |

REEL SPECIFICATION

| P/N | PKG | QTY |
|----------------|-----|------|
| US3A THRU US3M | SMC | 3000 |

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